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ULTRA FAST RECOVERY RECTIFIER DIODES

Glass-passivated, high-efficiency epitaxial rectifier diodes in DO-4 metal envelopes, featuring low forward voltage drop, ultra fast reverse recovery times, very low stored charge and soft recovery characteristic. They are intended for use in switched-mode power supplies and high-frequency circuits in general, where low conduction and switching losses are essential. The series consists of normal polarity (cathode to stud) types.

QUICK REFERENCE DATA

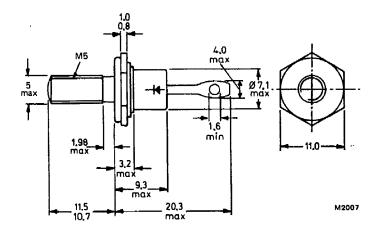
| | | | BYV30-300 | 400 | 500 | |
|---------------------------------|-----------------|------|-----------|------|-----|----|
| Repetitive peak reverse voltage | VRRM | max. | 300 | 400 | 500 | V |
| Average forward current | IF(AV) | max. | | 14 | | Α |
| Forward voltage | ٧F | < | | 1.05 | | V |
| Reverse recovery time | t _{rr} | < | | 50 | | ns |

MECHANICAL DATA

Dimensions in mm

Fig.1 DO-4 with metric (M5) stud as standard.

10-32 UNF is available upon request with suffix U (e.g. BYV30-400U).



Net mass: 6 g

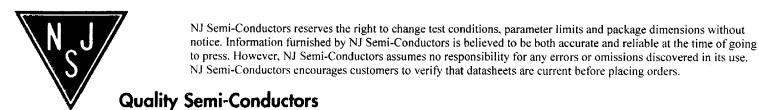
Diameter of clearance hole: max. 5.2 mm

Accessories supplied on request: see data sheets Mounting instructions and Accessories

for DO-4 envelopes.

Supplied with device: 1 nut, 1 lock washer. Nut dimensions across the flats: 9.5 mm

Torque on nut: min. 0.9 Nm (9 kg cm) max, 1.7 Nm (17 kg cm)



RATINGS
Limiting values in accordance with the Absolute Maximum System (IEC 134).

| | Voltages | | BYV30 | 300 | 400 | 500 | V | | |
|---|---|--------------------------------|--------------|------------------------|------------|-----------------|------------|---------|--|
| - | Non-repetitive peak reverse voltage | [∨] RSM | max. | 350 | 450 | 550 | ٧ | | |
| | Repetitive peak reverse voltage | VRRM | max. | 300 | 400 | 500 | V | | |
| | Crest working reverse voltage | V _{RWM} | max. | 200 | 300 | 400 | ٧ | | |
| | Continuous reverse voltage* VR | | max. | 200 | 300 | 400 | ٧ | | |
| | Currents | | | | · | | | | |
| | Average forward current; switching losses negligible up to 100 kHz | | | | | | | | |
| | square wave; δ = 0.5; up to $T_{mb} = 113 {}^{\circ}C$ up to $T_{mb} = 125 {}^{\circ}C$ | F(AV) | | max. max. | | 14 10 | | A A | |
| | sinusoidal; up to T _{mb} = 118 °C up to T _{mb} = 125 °C | IF(AV) IF(AV) | max. max. | | 12.5 10 | | A A | | |
| | R.M.S. forward current | ward current IF(RMS) | | max. | | 20 | | Α | |
| | Repetitive peak forward current $t_p = 20 \mu s$; $\delta = 0.02$ | FRM | max. | | 320 | | Α | | |
| | Non-repetitive peak forward current half sine-wave; T _j = 150 °C prior to surge; with reapplied V _{RWMmax} ; | | | | | | | | |
| | t = 10 ms t = 8.3 ms | IFSM IFSM | max. max. | | 150 180 | | A A | | |
| | $I^2 t$ for fusing (t = 10 ms) | 1²t | max. | | 1 | 12 | A²s | | |
| | Temperatures | | | | | | | | |
| | Storage temperature | e temperature T _{stg} | | -65 to +175 | | | οС | | |
| | Junction temperature | Tj | m | ax. | 150 | | оС | | |
| | THERMAL RESISTANCE | | | | | | | | |
| | From junction to mounting base Rth | | = | = | | 2.0 | K/W K/W | | |
| | From mounting base to heatsink with heatsink compound | R _{th mb-h} | = | | 0.3 50 | | | | |
| | From junction to ambient in free air | R _{th j-a} | | | | | | | |
| | CHARACTERISTICS | | | | | | - | | |
| | Forward voltage | | | | | | | | |
| | I _F = 15 A; T _j = 150 °C I _F = 50 A; T _j = 25 °C | | ۸Ł | | < | 1.05 1.40 | | V* - | |
| | Reverse current | | | | _ | ^^ | | A | |
| | $V_R = V_{RWM \text{ max}}$; $T_j = 100 ^{\circ}\text{C}$ $T_j = 25 ^{\circ}\text{C}$ | | IR < | | 0.8 50 | 0.8 mA 50 μA | | | |
| | Reverse recovery when switched from $I_F = 1 \text{ A to } \forall_R \geqslant 30 \text{ V with } -dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 ^{\circ}\text{C}; \text{ recovery time}$ $I_F = 2 \text{ A to } \forall_R \geqslant 30 \text{ V with } -dI_F/dt = 20 \text{ A/}\mu\text{s};$ $T_j = 25 ^{\circ}\text{C}; \text{ recovered charge}$ $I_F = 10 \text{ A to } \forall_R \geqslant 30 \text{ V with } -dI_F/dt = 50 \text{ A/}\mu\text{s};$ $T_j = 100 ^{\circ}\text{C}; \text{ peak recovery current}$ Forward recovery when switched to $I_F = 10 \text{ A with } dI_F/dt = 10 \text{ A/}\mu\text{s};$ $T_j = 25 ^{\circ}\text{C}$ | | | t _{rr} < | | 50 | 50 ns | | |
| | | | | o _s < | | 50 | 50 nC | | |
| | | | | I _{RRM} < | | 5.2 | 2 A | | |
| | | | | V _{fr} typ. 2 | | 2.5 | i v | | |
| | | | | | | | | | |